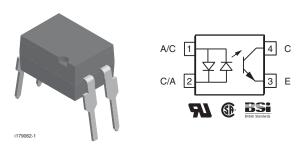


Vishay Semiconductors

Optocoupler, Phototransistor Output, AC Input, 5300 V_{RMS}



DESCRIPTION

The SFH620AA, SFH620AGB features a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm lead spacing. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation up to an operation voltage of 400 $\rm V_{RMS}$ or DC.

FEATURES

- High current transfer ratios
 - at 5 mA: 50 to 600 %
 - at 1.0 mA: 45 % typical (> 13)
- Low CTR degradation
- Good CTR linearity depending on forward current



- Isolation test voltage, 5300 V_{RMS}
- High collector emitter voltage, V_{CFO} = 70 V
- Low saturation voltage
- · Fast switching times
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity (unconnected base)
- SMD option, see SFH620A, SFH6206 datasheet
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- CSA 93751
- BSI IEC 60950; IEC 60065
- VDE 0884-5, DIN EN 60747-5-5, available with option 1

ORDERING INFORMATION					
S F H 6 2 0		0 1 DIP-4			
PART NUMBER	PACKAGE	E OPTION			
AGENCY CERTIFIED/PACKAGE	CTR (%)				
AGENCT CENTIFIED/FACKAGE	± 5 mA				
UL, CSA, BSI	50 to 600	100 to 600			
DIP-4	SFH620AA	SFH620AGB			
VDE, UL, CSA, BSI	/DE, UL, CSA, BSI 50 to 600				
DIP-4	-	SFH620AGB-X001			

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT	•						
DC forward current		I _F	± 60	mA			
Surge forward current	t _p ≤ 1.0 μs	I _{FSM}	± 2.5	Α			
Total power dissipation		P _{diss}	100	mW			
OUTPUT							
Collector emitter voltage		V _{CE}	70	V			
Emitter collector voltage		V _{EC}	7	V			
Collector current		I _C	50	mA			
Collector Current	t _p ≤ 1.0 ms	I _C	100	mA			
Power dissipation		P_{diss}	150	mW			

Rev. 1.8, 19-Nov-14 **1** Document Number: 83676



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
COUPLER						
Isolation test voltage between emitter and detector		V _{ISO}	5300	V _{RMS}		
Creepage distance			≥ 7	mm		
Clearance distance			≥ 7	mm		
Insulation thickness between emitter and detector			≥ 0.4	mm		
Comparative tracking index per DIN IEC 112/VDE 0303 part 1		CTI	≥ 175			
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω		
Isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω		
Storage temperature		T _{stg}	-55 to +150	°C		
Ambient temperature		T _{amb}	-55 to +100	°C		
Junction temperature		Tj	100	°C		
Soldering temperature (1)	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T _{sld}	260	°C		

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	$I_F = \pm 60 \text{ mA}$		V_{F}		1.25	1.65	V	
Capacitance	V _R = 0 V, f = 1 MHz		Co		50		pF	
Thermal resistance			R _{thja}		750		K/W	
OUTPUT								
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz		C _{CE}		6.8		pF	
Thermal resistance			R _{thja}		500		K/W	
COUPLER	·							
Collector emitter saturation voltage	$I_F = \pm 10 \text{ mA}, I_C = 2.5 \text{ mA}$		V _{CEsat}		0.25	0.4	V	
Coupling capacitance			C _C		0.2		pF	
Collector emitter leakage current	V - 10 V	SFH620AA	I _{CEO}		10	100	nA	
Collector emitter leakage current	V _{CE} = 10 V	SFH620AGB	I _{CEO}		10	100	nA	

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
1.71	1 - 1 5 m \ \ \ - 5 \	SFH620AA	CTR	50		600	%
I _C /I _F	$I_F = \pm 5 \text{ mA}, V_{CE} = 5 \text{ V}$	SFH620AGB	CIR	100		600	%

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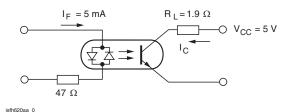


Fig. 1 - Switching Times (Typical Values) Linear Operation (Saturated)

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER TEST CONDITION SYMBOL MIN. TYP. MAX. UNIT						
Turn-on time	$I_F=\pm~5~mA,~R_L=1.9~k\Omega,~V_{CC}=5~V$	t _{on}		2		μs
Turn-off time	$I_F=\pm~5~mA,~R_L=1.9~k\Omega,~V_{CC}=5~V$	t _{off}		25		μs

SAFETY AND INSULATION RATINGS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Climatic classification (according to IEC 68 part 1)				55/100/21				
Comparative tracking index		CTI	175		399			
V _{IOTM}			10000			V		
V _{IORM}			890			V		
P _{SO}					400	mW		
I _{SI}					275	mA		
T _{SI}					175	°C		
Creepage distance	standard DIP-4		7			mm		
Clearance distance	standard DIP-4		7			mm		
Insulation thickness, reinforced rated	per IEC 60950 2.10.5.1		0.4			mm		

Note

 As per IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

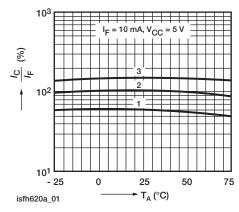


Fig. 2 - Current Transfer Ratio (CTR) vs. Temperature

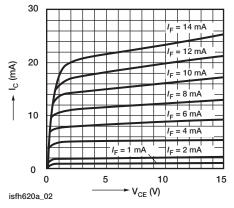


Fig. 3 - Output Characteristics (Typ.) Collector Current vs. Collector Emitter Voltage



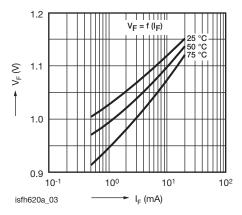


Fig. 4 - Diode Forward Voltage (Typ.) vs. Forward Current

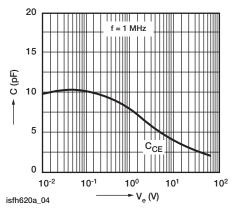


Fig. 5 - Transistor Capacitance (Typ.) vs. Collector Emitter Voltage

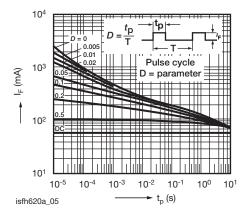


Fig. 6 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

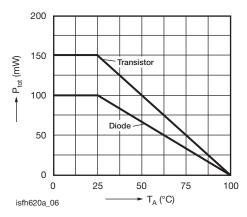


Fig. 7 - Permissible Power Dissipation vs. Ambient Temperature

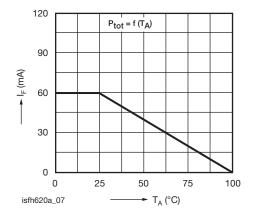
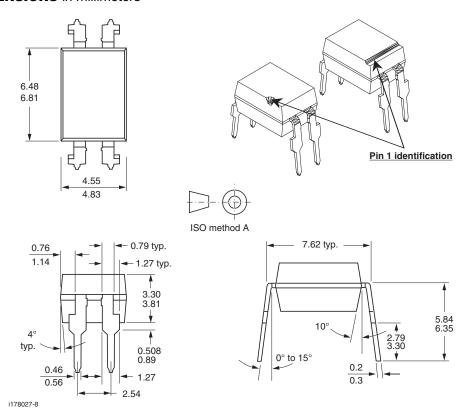


Fig. 8 - Permissible Diode Forward Current vs.
Ambient Temperature

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PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (example of SFH620AGB-X001)



Note

• The VDE logo is only marked on option1 parts.

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